

TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE (PCT PROCESS)

2SB553

HIGH CURRENT SWITCHING APPLICATIONS.
POWER AMPLIFIER APPLICATIONS.

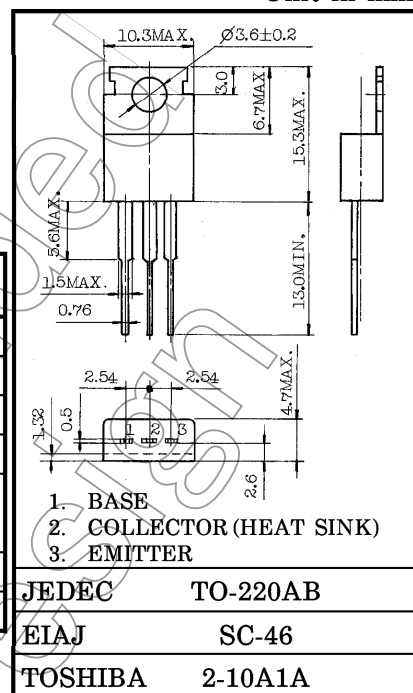
INDUSTRIAL APPLICATIONS

Unit in mm

- Low Collector Saturation Voltage
: $V_{CE(sat)} = -0.4V$ (Max.) at $I_C = -4A$
- Complementary to 2SD553.

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-70	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-7	A
Collector Power Dissipation	P_C	1.5	W
		40	
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55~150	$^\circ C$

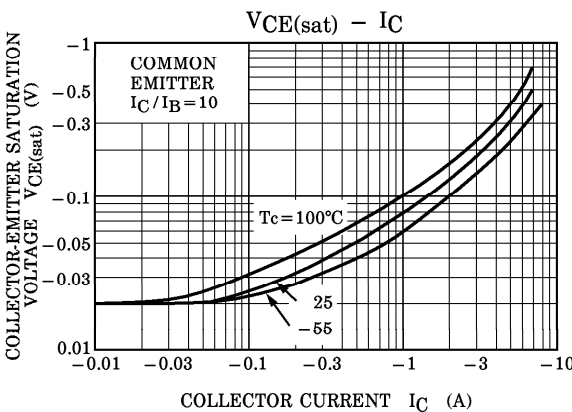
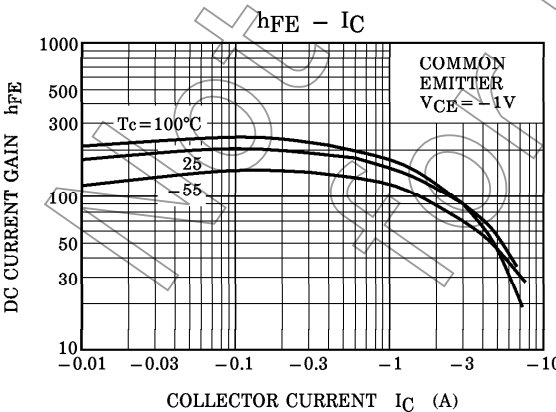
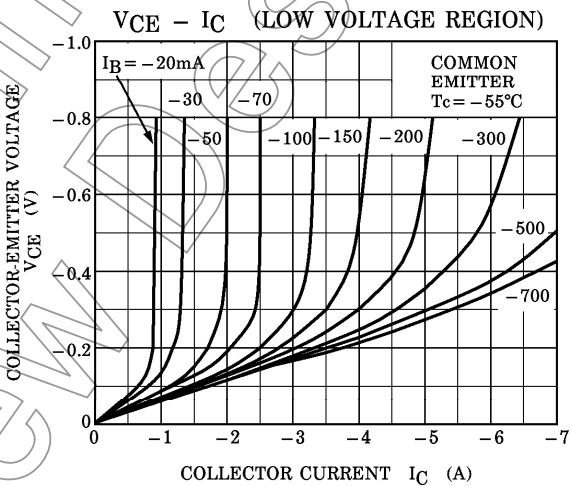
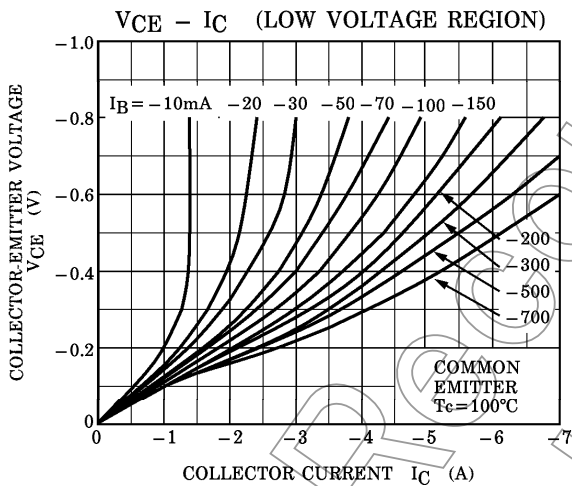
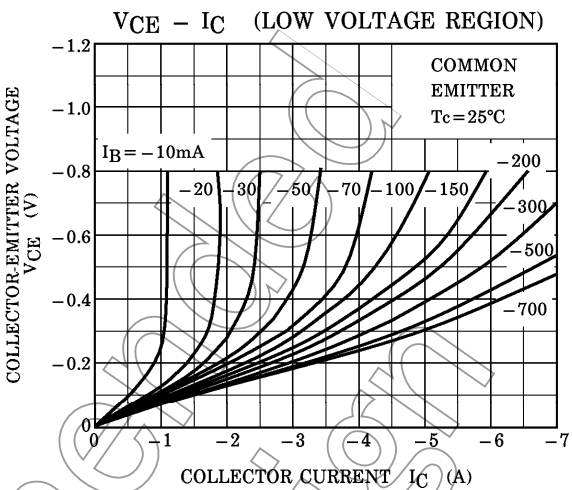
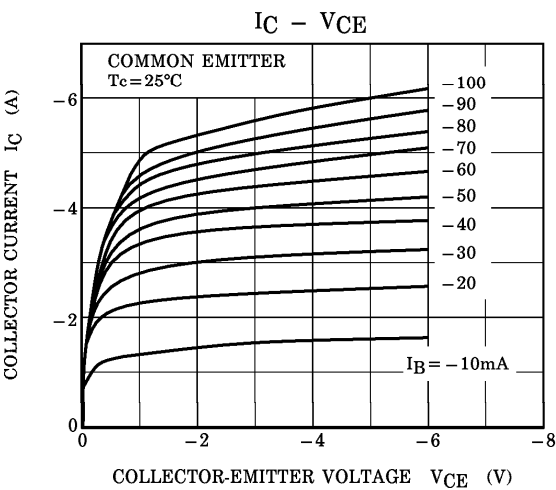


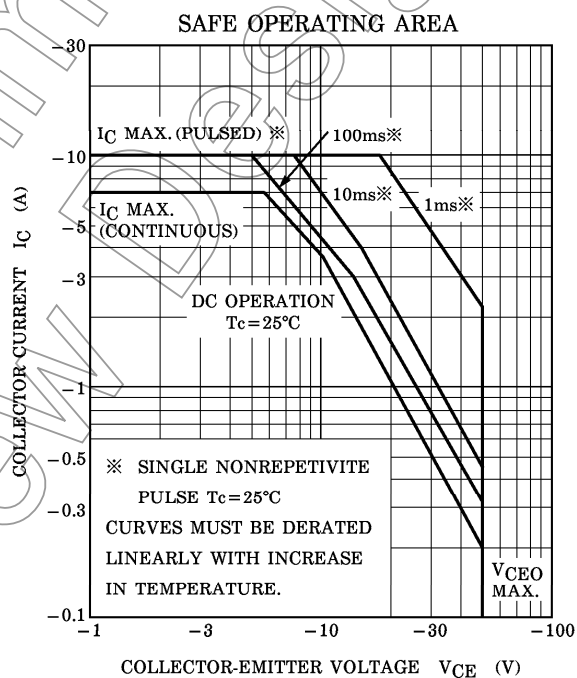
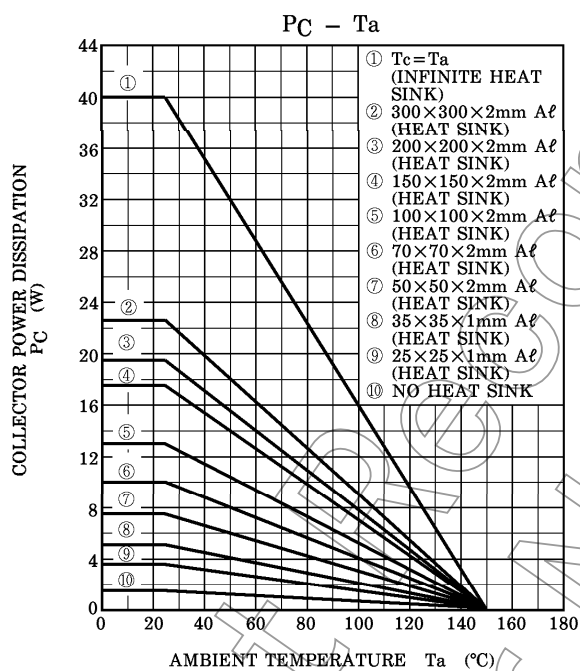
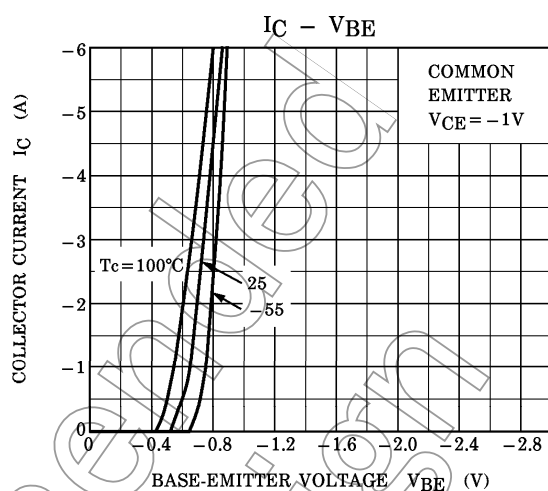
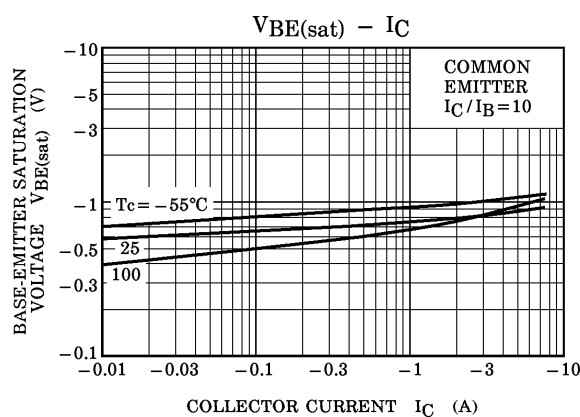
Mounting Kit No. AC75
Weight : 1.9g

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -70V, I_E = 0$	—	—	-30	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5V, I_C = 0$	—	—	-50	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -50mA, I_B = 0$	-50	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE} = -1V, I_C = -1A$	70	—	240	
	$h_{FE(2)}$	$V_{CE} = -1V, I_C = -4A$	30	—	—	
Saturation Voltage	Collector-Emitter	$V_{CE(sat)}$ $I_C = -4A, I_B = -0.4A$	—	-0.2	-0.4	V
	Base-Emitter	$V_{BE(sat)}$ $I_C = -4A, I_B = -0.4A$	—	-0.9	-1.2	
Transition Frequency	f_T	$V_{CE} = -4V, I_C = -1A$	—	10	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$	—	250	—	pF
Switching Time	Turn-on Time	t_{on}	—	0.2	—	μs
	Storage Time	t_{stg}	—	2.5	—	
	Fall Time	t_f	—	0.5	—	

Note : $h_{FE(1)}$ Classification O : 70~140, Y : 120~240





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